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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/765,388	01/22/2001	Nobuo Shimazu	740107-140	1026
22204 7	590 02/13/2003			
NIXON PEA	•		EXAM	INER
8180 GREENSBORO DRIVE SUITE 800			VANORE, DAVID A	
MCLEAN, VA	. 22102		ART UNIT	PAPER NUMBER
			2881	
			DATE MAILED: 02/13/2003	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)			
	•	09/765,388	SHIMAZU ET AL.			
ir	Office Action Summary	Examiner	Art Unit			
		David A Vanore	2881			
Period fo	The MAILING DATE of this communication ap or Reply		i i			
THE I - Exter after - If the - If NO - Failui - Any r	ORTENED STATUTORY PERIOD FOR REPL MAILING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.7 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a repiperiod for reply is specified above, the maximum statutory period to teply within the set or extended period for reply will, by statute eply received by the Office later than three months after the mailing dispatent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply by within the statutory minimum of thirty (3) will apply and will expire SIX (6) MONTH: b. cause the application to become ABAN	by be timely filed 0) days will be considered timely. 5 from the mailing date of this communication.			
1) 🗌	Responsive to communication(s) filed on	·				
2a) <u></u>	This action is FINAL . 2b)⊠ Th	nis action is non-final.				
3)□ Dispositi	Since this application is in condition for allow closed in accordance with the practice under on of Claims	ance except for formal matter Ex parte Quayle, 1935 C.D.	rs, prosecution as to the merits is 11, 453 O.G. 213.			
4) 🖾	Claim(s) 1-6 is/are pending in the application.					
<u>'</u>	4a) Of the above claim(s) is/are withdrawn from consideration.					
5)	Claim(s) is/are allowed.					
6)⊠	Claim(s) <u>1-6</u> is/are rejected.					
7) 🗌	Claim(s) is/are objected to.					
	Claim(s) are subject to restriction and/o	r election requirement.				
9)□ T	he specification is objected to by the Examine	r.				
10)⊠ T	he drawing(s) filed on 22 January 2001 is/are:	a) accepted or b) objected	d to by the Examiner.			
	Applicant may not request that any objection to the	e drawing(s) be held in abeyance	e. See 37 CFR 1.85(a).			
11)∐ T	he proposed drawing correction filed on	_ is: a) ☐ approved b) ☐ disa	pproved by the Examiner.			
	If approved, corrected drawings are required in rep	oly to this Office action.				
12) 🗌 T	he oath or declaration is objected to by the Ex	aminer.				
Priority u	nder 35 U.S.C. §§ 119 and 120					
13) 🔲 🗸	Acknowledgment is made of a claim for foreigr	priority under 35 U.S.C. § 1	19(a)-(d) or (f).			
a)[All b) Some * c) None of:					
•	1. Certified copies of the priority documents	s have been received.				
2	2. Certified copies of the priority documents have been received in Application No					
	Copies of the certified copies of the prior application from the International But the of the other data lied.	reau (PCT Rule 17.2(a)).	_			
	ee the attached detailed Office action for a list					
	cknowledgment is made of a claim for domestic					
15)∏ A	The translation of the foreign language procknowledgment is made of a claim for domesti					
Attachment(
2) Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-948) ation Disclosure Statement(s) (PTO-1449) Paper No(s) <u>6</u> .	5) Notice of Inform	mary (PTO-413) Paper No(s) mal Patent Application (PTO-152)			
S. Patent and Trac TO-326 (Rev.		tion Summary	Part of Paper No. 7			

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Claim Rejections - 35 USC § 112

The following is a quotation of the second paragraph of 35 U.S.C. 112:

The specification shall conclude with one or more claims particularly pointing out and distinctly claiming the subject matter which the applicant regards as his invention.

Claims 3 and 6 are rejected under 35 U.S.C. 112, second paragraph, as being indefinite for failing to particularly point out and distinctly claim the subject matter which applicant regards as the invention.

The term "satisfactorily" in claims 3 and 6 line 3 is a relative term which renders the claim indefinite. The term "satisfactorily" is not defined by the claim, the specification does not provide a standard for ascertaining the requisite degree, and one of ordinary skill in the art would not be reasonably apprised of the scope of the invention. Using the term "satisfactorily" to define the dimension of a beam in a charged particle lithography device because the terms meaning is subjective in nature. What is satisfactory in the context of the present invention? Is there a range of beam dimensions associated with what the applicant regards as satisfactory?

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 1, 2, and 5 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Stengl et al.

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Stengl et al. teaches an electron beam exposure apparatus and associated method of use comprising an electron source (Q and Col. 2 Lines 53-57), an electron beam shaping means comprising an electrostatic cylindrical lens (Elsub1 through Elsubn in Fig. 2 and Col. 2 Lines 31-36) as recited in claim 2, a mask having a plurality of apertures (M) in proximity to a sample, a deflecting and scanning means (Fig. 4 and Fig. 5 Item MP Col. 8 Lines 54-Col. 9 Line 9), a stage (S), where the beam is shaped to have a cross section in the plane of the sample which is smaller that the cross section in a plane extending vertically and perpendicular from the sample (Col. 8 Lines 54-Col. 9 Line 9) as recited in claims 1, 2, and 5.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3, 4, and 6 are rejected under 35 U.S.C. 103(a) as being unpatentable over Stengl et al. in view of Muraki et al.

Stengl et al. teaches all limitations as applied above but fails to explicitly teach an electron beam lithography device having an interval in between adjacent scan lines in an exposure process, and each portion of a pattern is exposed by scanning an electron beam at least five times as recited in claims 3, 4, and 6.

Muraki et al. teaches an electron beam lithography device where each exposure region in a scan line has an interval between a subsequent scan line (Fig. 6B). Muraki

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et al. also teaches a device where each element which comprises a pattern is scanned any number of required times to effect total pattern exposure. Regarding claim 4, given that there are more pattern elements in the example of Fig. 6B, Muraki et al. clearly teaches that a total pattern is produced in more than five exposures because there are clearly more than five pattern elements. (Col. 15 Lines 10-25)

Muraki et al. modifies the device and method of Stengl et al. to produce a device which exposes a pattern having a plurality of pattern elements with an interval between them, the exposure of the pattern being carried out by exposing a substrate to a plurality of scans on the surface of a substrate by an electron beam.

It would have been obvious to one having ordinary skill in the art at the time the invention was made to provide an interval between scanning regions or pattern elements on a substrate for exposure in a multiple pass electron beam lithography device because, not only are these limitations taught by Muraki et al., but the configuration of pattern elements to be exposed and the amount of scans required by an electron beam are a function of the pattern, chosen by the practitioner of the invention. For example, one could select a pattern having any amount of desired space within a given pattern for exposure, such as in a SEM metrology standard where a plurality of raised lines are scribed into a substrate with differing distances between said lines. Secondly, the exposing of a pattern multiple times could be a function of reducing proximity effect, the depth and complexity of the pattern to be exposed, or the size and number of partitions in a total pattern selected to be exposed. The recited limitations are taught by Muraki et al. as cited above.

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Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

The following US Patents teach lithography devices and methods relating to the present invention:

US Patent 5,874,739 (Bushbeck et al.); US Patent 5,391,886 (Yamada et al.);

US Patent 5,770,862 (Ooaeh et al.); and US Patent 4,963,748 (Szilagyi);

Any inquiry concerning this communication or earlier communications from the examiner should be directed to David A Vanore whose telephone number is 703-306-0246. The examiner can normally be reached on M-F 7:30-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, John Lee can be reached on 703-308-4116. The fax phone numbers for the organization where this application or proceeding is assigned are 703-872-9318 for regular communications and 703-872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

dav January 29, 2003

JOHN R. LEE

SUPERIOSORY PATENT SYMMER

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